DISCRETE SEMICONDUCTORS



Product specification Supersedes data of November 1993 1996 Apr 26



PMLL5225B to PMLL5267B

FEATURES

- Total power dissipation: max. 500 mW
- Tolerance series: ±5%
- Working voltage range: nom. 3.0 to 75 V
- Non-repetitive peak reverse power dissipation: max. 40 W.

APPLICATIONS

• Low-power voltage stabilizers or voltage references.

DESCRIPTION

Low-power voltage regulator diodes in small hermetically sealed glass SOD80C SMD packages. The series consists of 43 types with nominal working voltages from 3.0 to 75 V.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER CONDITIONS		MIN.	MAX.	UNIT
I _F	continuous forward current		_	250	mA
I _{ZSM}	non-repetitive peak reverse current $t_p = 100 \ \mu s$; square wave; $T_i = 25 \ ^\circ C$ prior to surge		see Table "Per type"		
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	-	500	mW
P _{ZSM}	non-repetitive peak reverse power dissipation	$t_p = 100 \ \mu s$; square wave; T _j = 25 °C prior to surge; see Fig.3	_	40	W
		t_p = 8.3 ms; square wave; T _j ≤ 55 °C prior to surge	_	10	W
T _{stg}	storage temperature		-65	+200	°C
Tj	junction temperature		-65	+200	°C

Note

1. If flanges are kept at $T_{flange} \le 75 \ ^{\circ}C$.

ELECTRICAL CHARACTERISTICS

Total series

 $T_i = 25 \ ^{\circ}C$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _F	forward voltage	I _F = 200 mA; see Fig.4	-	1.1	V

PMLL5225B to PMLL5267B

Product specification

Per type $T_j = 25 \ ^{\circ}C$; unless otherwise specified.

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TYPE No	WORKING VOLTAGE V _z (V) ⁽¹⁾	DIFFERENTIAL RESISTANCE r _{dif} (Ω) at I _{Ztest}	TEMP. COEFF. S _Z (%/K) at Iz ⁽²⁾	TEST CURRENT I _{Ztest} (mA)	DIODE CAP. C _d (pF) at f = 1 MHz;	REVERSE CURRENT at REVERSE VOLTAGE		NON-REPETITIVE PEAK REVERSE CURRENT IZSM (A)	
	at I _{Ztest}				at V _R = 0 V	I _R (μΑ)	V _R	at t _p = 100 µs; T _{amb} = 25 °C	
	NOM.	MAX.	MAX.		MAX.	MAX.	(V)	MAX.	
PMLL5225B	3.0	1600	-0.075	20	450	50	1.0	6.0	
PMLL5226B	3.3	1600	-0.070	20	450	25	1.0	6.0	
PMLL5227B	3.6	1700	-0.065	20	450	15	1.0	6.0	
PMLL5228B	3.9	1 900	-0.060	20	450	10	1.0	6.0	
PMLL5229B	4.3	2000	±0.055	20	450	5	1.0	6.0	
PMLL5230B	4.7	1 900	±0.030	20	450	5	1.5	6.0	
PMLL5231B	5.1	1600	±0.030	20	300	5	2.0	6.0	
PMLL5232B	5.6	1600	+0.038	20	300	5	3.0	6.0	
PMLL5233B	6.0	1600	+0.038	20	300	5	3.5	6.0	
PMLL5234B	6.2	1000	+0.045	20	200	5	4.0	6.0	
PMLL5235B	6.8	750	+0.050	20	200	3	5.0	6.0	
PMLL5236B	7.5	500	+0.058	20	150	3	6.0	4.0	
PMLL5237B	8.2	500	+0.062	20	150	3	6.5	4.0	
PMLL5238B	8.7	600	+0.065	20	150	3	6.5	3.5	
PMLL5239B	9.1	600	+0.068	20	150	3	7.0	3.0	
PMLL5240B	10	600	+0.075	20	90	3	8.0	3.0	
PMLL5241B	11	600	+0.076	20	85	2	8.4	2.5	
PMLL5242B	12	600	+0.077	20	85	1	9.1	2.5	
PMLL5243B	13	600	+0.079	9.5	80	0.5	9.9	2.5	
PMLL5244B	14	600	+0.082	9.0	80	0.1	10.0	2.0	
PMLL5245B	15	600	+0.082	8.5	75	0.1	11.0	2.0	
PMLL5246B	16	600	+0.083	7.8	75	0.1	12.0	1.5	
PMLL5247B	17	600	+0.084	7.4	75	0.1	13.0	1.5	
PMLL5248B	18	600	+0.085	7.0	70	0.1	14.0	1.5	
PMLL5249B	19	600	+0.086	6.6	70	0.1	14.0	1.5	
PMLL5250B	20	600	+0.086	6.2	60	0.1	15.0	1.5	

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TYPE No.	$\begin{array}{c c c c c c c c c c c c c c c c c c c $		TEST CURRENT I _{Ztest} (mA)	DIODE CAP. C _d (pF) at f = 1 MHz;	REVERSE CURRENT at REVERSE VOLTAGE		NON-REPETITIVE PEAK REVERSE CURRENT I _{ZSM} (A)	
	at I _{Ztest}	at I _{Ztest}			at $V_R = 0 V$	I _R (μΑ)	V _R	at $t_p = 100 \ \mu s$; $I_{amb} = 25 \ ^{\circ}C$
	NOM.	MAX.	MAX.		MAX.	MAX.	(V)	MAX.
PMLL5251B	22	600	+0.087	5.6	60	0.1	17.0	1.25
PMLL5252B	24	600	+0.088	5.2	55	0.1	18.0	1.25
PMLL5253B	25	600	+0.089	5.0	55	0.1	19.0	1.25
PMLL5254B	27	600	+0.090	4.6	50	0.1	21.0	1.0
PMLL5255B	28	600	+0.091	4.5	50	0.1	21.0	1.0
PMLL5256B	30	600	+0.091	4.2	50	0.1	23.0	1.0
PMLL5257B	33	700	+0.092	3.8	45	0.1	25.0	0.9
PMLL5258B	36	700	+0.093	3.4	45	0.1	27.0	0.8
PMLL5259B	39	800	+0.094	3.2	45	0.1	30.0	0.7
PMLL5260B	43	900	+0.095	3.0	40	0.1	33.0	0.6
PMLL5261B	47	1 000	+0.095	2.7	40	0.1	36.0	0.5
PMLL5262B	51	1100	+0.096	2.5	40	0.1	39.0	0.4
PMLL5263B	56	1 300	+0.096	2.2	40	0.1	43.0	0.3
PMLL5264B	60	1 400	+0.097	2.1	40	0.1	46.0	0.3
PMLL5265B	62	1 400	+0.097	2.0	35	0.1	47.0	0.3
PMLL5266B	68	1600	+0.097	1.8	35	0.1	52.0	0.25
PMLL5267B	75	1700	+0.098	1.7	35	0.1	56.0	0.2

Notes

1. V_Z is measured with device at thermal equilibrium while held in clips at 10 mm from body in still air at 25 °C.

2. For types PMLL5225B to PMLL5242B the I_Z current is 7.5 mA; for PMLL5243B and higher I_Z = I_{Ztest}. S_Z values valid between 25 °C and 125 °C.

Voltage regulator diodes

PMLL5225B to PMLL5267B

PMLL5225B to PMLL5267B

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point	lead length 10 mm	300	K/W
R _{th j-a}	thermal resistance from junction to ambient	lead length max.; see Fig.2 and note 1	380	K/W

Note

1. Device mounted on a printed circuit-board without metallization pad.

PMLL5225B to PMLL5267B

GRAPHICAL DATA







PMLL5225B to PMLL5267B

PACKAGE OUTLINE



DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values					
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification					

Application information

Where application information is given, it is advisory and does not form part of the specification.

is not implied. Exposure to limiting values for extended periods may affect device reliability.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.